# **UltraThin Ceramic Capacitors**

### **UT Series**





The Ultrathin (UT) series of ceramic capacitors is a new product offering from AVX. The UT series was designed to meet the stringent thickness requirements of our customers. AVX developed a new termination process (FCT - Fine Copper Termination) that provides unbeatable flatness and repeatability. The series includes products < 0.35mm in height and is targeted for applications such as Smart cards, Memory modules, High Density SIM cards, Mobile phones, MP3 players, and embedded solutions.

#### **HOW TO ORDER**

02

UT

		•	
Τ	Τ	Ţ	Ţ
Style Ultra Thin	Case Size 0402	<b>Rated</b> <b>Voltage</b> 6 = 6.3V Z = 10V Y = 16V 3 = 25V 5 = 50V	Temperature Characteristic D = X5R C = X7R

3



Cap Termination Tolerance Style ± 20% Commercial

Α

mm (inches)

Μ



Т



E = 0.25mm max F = 0.15mm max (only available in Cu Termination)

D





#### ► BL BL Top View Side View End View Т

D

#### **TYPICAL Cu THICKNESS**

	TT	
μΜ	$10.0 \pm 4.00$	
mil	0.40 ± 0.16	



#### PART DIMENSIONS

Thickness	L	W	Т	BL
D	1.00 ± 0.10	0.50 ± 0.10	0.25 ± 0.05	0.27 ± 0.05
	(0.039±0.004)	(0.020 ± 0.004)	(0.010 ± 0.002)	(0.0108 ± 0.002)
E	1.00 ± 0.10	0.50 ± 0.10	0.20 ± 0.05	0.27 ± 0.05
	(0.039±0.004)	(0.020 ± 0.004)	(0.008 ± 0.002)	(0.0108 ± 0.002)
F	1.00 ± 0.10	0.50 ± 0.10	0.125 ± 0.025	0.27 ± 0.05
	(0.039±0.004)	(0.020 ± 0.004)	(0.005 ± 0.001)	(0.0108 ± 0.002)

### CAP RANGE (THICKNESS CODE)

X5R	Thickness Code									
ASH		_	D	_	-	E		F		
Cap (nF)	6.3V	10V	16V	25V	50V	6.3V	10V	16V	6.3V	10V
1										
10										
22										
33										
47										
68										
100										

X7B	Thickness Code					
A/R		F				
Cap (nF)	6.3V	10V	16V	25V	6.3V	
1						
10						



# **UltraThin Ceramic Capacitors**



## UT Series Specifications and Test Methods – Cu Termination

Parameter/Test		Specification Limits	Measuring Conditions		
Operating Temperature Range		-55°C to +85°C	Temperature Cycle Chamber		
Capacitance		Within specified tolerance	Freq.: 1.0 kHz ± 10%		
Dissipatio	on Factor	$\leq$ 3.0% for $\geq$ 25V DC rating	Voltage: 1.0Vrms ± .2V		
Dissipatio		$\leq$ 12.5% for $\leq$ 16V DC rating			
Insulation Resistance		100 MΩ - μF	Charge device with rated voltage for $120 \pm 5$ secs @ room temp/humidity		
Dielectric	Strength	No breakdown or visual defects	Charge device with 300% of rated voltage for 1-5 seconds, with charge and discharge current limited to 50 mA (max)		
	Appearance	No defects	Deflection: 2mm		
	Capacitance	≤ ±12%	Test Time: 30 seconds		
Resistance to	Variation	S 1 1 2 70	1mm/sec		
FlexureDissipationStressesFactorInsulationResistance		Meets Initial Values (As Above)			
		≥ Initial Value x 0.3	90 mm		
	Appearance	No visual defects			
Capacitance Variation Dissipation Factor		$\leq \pm 20\%$	Charge device with 1.5X rated voltage in test chamber set at 85°C ± 2°C for 1000 hours (+48, -0)		
		$\leq$ Initial Value x 2.0 (As Above)			
	Insulation Resistance	≥ Initial Value x 0.3 (As Above)	Remove from test chamber and stabilize at room temperature for $24 \pm 2$ hours		
Dielectric Strength		Meets Initial Values (As Above)	before measuring.		

# **UltraThin Ceramic Capacitors**



## UT Series Specifications and Test Methods – Sn Termination

Parameter/Test		Specification Limits	Measuring Conditions		
Operating Temperature Range		-55°C to +85°C	Temperature Cycle Chamber		
Capacitance		Within specified tolerance			
		$\leq$ 3.0% for $\geq$ 25V DC rating	Freq.: 1.0 kHz $\pm$ 10%		
Dissipation Factor		$\leq$ 12.5% for $\leq$ 16V DC rating	Voltage: 1.0Vrms ± 0.2V		
Insulation Resistance		100 MΩ - μF	Charge device with rated voltage for 120 ± 5 secs @ room temp/humidity		
Dielectric Strength		No breakdown or visual defects	Charge device with 300% of rated voltage for 1-5 seconds, with charge and discharge current limited to 50 mA (max)		
	Appearance	No defects	Deflection: 2mm		
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 30 seconds		
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)			
	Insulation Resistance	≥ Initial Value x 0.3	90 mm		
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic solder at $245 \pm 5^{\circ}$ C for 5.0 $\pm$ 0.5 seconds		
	Appearance	No defects, <25% leaching of either end terminal			
	Capacitance Variation	$\leq \pm 7.5\%$	Dip device in eutectic solder at 260°C for 60		
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	seconds. Store at room temperature for $24 \pm 2$ hours before measuring electrical properties		
Solder Heat	Insulation Resistance	Meets Initial Values (As Above)	nours before measuring electrical properties.		
Dielectric Strength		Meets Initial Values (As Above)			
	Appearance	No visual defects			
Load Life Capacitance Variation Dissipation Factor Insulation Resistance		≤ ±12%	Charge device with 1.5X rated voltage in test chamber set at		
		$\leq$ Initial Value x 2.0 (As Above)	85°C ± 2°C for 1000 hours (+48, -0)		
		≥ Initial Value x 0.3 (As Above)	Remove from test chamber and stabilize at room temperature for $24 \pm 2$ hours		
	Dielectric Strength	Meets Initial Values (As Above)	before measuring.		
Appearance Capacitance Variation		No visual defects	Store in a test chamber set at $85^{\circ}C \pm 2^{\circ}C/$		
		≤ ±12%	$85\% \pm 5\%$ relative humidity for 1000 hours (+48, -0) with rated voltage applied.		
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (As Above)	Remove from chamber and stabilize at		
	Insulation Resistance	≥ Initial Value x 0.3 (As Above)	room temperature and humidity for $24 \pm 2$ hours before measuring.		
	Dielectric Strength	Meets Initial Values (As Above)			